



Features

- ◊ Fast Switching Speed
- ◊ For General Purpose Switching Applications
- ◊ High Conductance

Marking MMBD4148T: KA2, BAS16T:A2

Dimensions in inches and (millimeters)

Maximum Ratings @ $T_A=25^\circ\text{C}$

Parameter	Symbol	Limits		Unit
Non-Repetitive Peak reverse voltage	V_{RM}	100		V
Peak Repetitive Peak reverse voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	75		V
RMS Reverse Voltage	$V_{R(RMS)}$	53		V
Forward Continuous Current	I_{FM}	300		mA
Average Rectified Output Current	I_O	150		mA
Peak forward surge current @=1.0μs @=1.0s	I_{FSM}	2.0 1.0		A
Power Dissipation	P_d	200		mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	625		K/W
Junction temperature	T_j	150		°C
Storage temperature	T_{STG}	-65~+150		°C

Electrical Ratings @ $T_A=25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	$V_{(BR) R}$	75			V	$I_R=1\mu\text{A}$
Forward voltage	V_{F1}			0.715	V	$I_F=1\text{mA}$
	V_{F2}			0.855	V	$I_F=10\text{mA}$
	V_{F3}			1.0	V	$I_F=50\text{mA}$
	V_{F4}			1.25	V	$I_F=150\text{mA}$
Reverse current	I_{R1}			1	μA	$V_R=75\text{V}$
	I_{R2}			25	nA	$V_R=20\text{V}$
Capacitance between terminals	C_T			2	pF	$V_R=0\text{V}, f=1\text{MHz}$
Reverse Recovery Time	t_{rr}			4	ns	$I_F=I_R=10\text{mA}$ $I_{rr}=0.1X I_R, R_L=100\Omega$

Typical Characteristics

